## General Description

The IZ1583 is a step-down regulator with a built in internal power MOSFET. The IC provide 3A continuous output current over a wide supply voltage range. The IC can be used as distributed power source, battery charger, pre-regulator for linear regulators.

## Features

- Wide supply voltage range $4,75 \ldots 23 \mathrm{~V}$.
- Wide operating temperature range $-40 \ldots+85^{\circ} \mathrm{C}$.
- Active mode consumption current (max.) $1,2 \mathrm{~mA}$.
- Chip dimensions $1,91 \times 1,42 \mathrm{~mm}$.
- ICs are available for shipment in chip form on unsawn wafers


## - Functionality

IC performs driving of power built in MOSFET switch, quantity of energy transferred to load is regulated by means of MOSFET on-time (pulse-width modulation). So ouput voltage practically do not depends from load.

Table 1 - Contact pad description

| Pad number | Symbol | Description |
| :---: | :---: | :--- |
| 01 | BS | n-channel power output MOSFET switch drive input |
| 02 V | cC | IC supply pin. Connected to 6,5V ... 32 V power source. Bypass Vcc <br> to GND with a suitably large capacitor to eliminate noise on the input <br> to the IC. |
| 03 | SW | Power switch output. SW has to be connected by output LC filter to <br> the output load and by mentioned capacitor to BS. |
| 04 | GND | Common pin (ground) |
| 05 FB |  | Feedback Input, has to be connected by a resistive voltage divider to <br> output voltage, |
| 06 | COMP | Frequency compensation Node has to be connected by series RC net- <br> work to GND |
| 07 | EN | Digital enable/disable input. High level applied to EN turns IC ON <br> and low level - turns it OFF. For automatic startup, leave EN uncon- <br> nected. |
| 08 | SS | Soft Start. SS is purposed to control the soft start period. To set soft <br> start mode connect SS \& GND by capacitor. A 0.1 $\mu \mathrm{F}$ capacitor sets <br> the soft-start period to 10ms. To disable the soft-start feature, leave SS <br> unconnected. |



Fig. 1 - Electric block diagram

Table 2 - Maximum \& Absolute Maximum Ratings

| Parameter, unit | Symbol | Recommended Operating Conditions |  | Absolute Maximum Ratings |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Norm |  | Norm |  |
|  |  | Min. Mdx. |  | Min. | Max. |
| Supply Voltage, V | $\mathrm{U}_{\mathrm{CC}} 4,7$ |  | 23 | -0,3 | 28 |
| SW Pin Voltage, V | $\mathrm{U}_{\text {SW }}$ | - | - | -1,0 | $\mathrm{U}_{\mathrm{CC}}+0,3$ |
| BS Pin Voltage, V | $\mathrm{U}_{\mathrm{BS}}$ - |  | - | $\mathrm{USW}-0,3$ | $\mathrm{U}_{\mathrm{SW}}+6,0$ |
| Junction Temperature | $\mathrm{T}_{\mathrm{J}}$ |  |  | -40* | 150 |
| Thermal; resistance «junction ambient», ${ }^{\circ} \mathrm{C} / \mathrm{W}$ | $\mathrm{R}_{\text {th }} \mathrm{j}$-a | 150 |  |  |  |
| Ambient Temperature, ${ }^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{A}}$ - | 40 | 85 |  |  |

Note - Maximum permissible power $\mathrm{P}_{\text {tot }}$, W , dissipated by IC in conditional package for ambient temperature $\mathrm{T}_{\mathrm{A}},{ }^{\circ} \mathrm{C}$, is calculated by formula:

$$
\begin{equation*}
P_{t o t}=\frac{125-T_{A}}{R_{t h j-a}}, \tag{1}
\end{equation*}
$$

125 - is maximum permissible operating junction temperature, ${ }^{\circ} \mathrm{C}$;
$\mathrm{R}_{\mathrm{th} j \text {-a }}$ - thermal resistance junction-ambient of IC (without heatsink).

Table 3 - Electric parameters of IC IZ1583 (on default $\mathrm{U}_{\mathrm{CC}}=12 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Parameter, unit | Symbol | Measurement mode | Norm |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Max |
| Shutdown Supply Current, uA | $\mathrm{I}_{\text {SD }}$ | $\mathrm{U}_{\text {EN }}=0 \mathrm{~V}$ |  | 30 |
| Supply Current, mA | Is | $\begin{aligned} & \mathrm{U}_{\mathrm{EN}}=2,6 \mathrm{~V} \\ & \mathrm{U}_{\mathrm{FB}}=1,4 \mathrm{~V} \\ & \hline \end{aligned}$ |  | 1,2 |
| Feedback Voltage, V | $\mathrm{U}_{\text {FB }}$ | $4,75 \mathrm{~V} \leq \mathrm{U}_{\mathrm{CC}} \leq 23 \mathrm{~V}$ | 1,194 | 1,250 |
| Error amplifier transconductance, uA/V | S | $\Delta \mathrm{I}_{\text {COMP }}= \pm 10 \mathrm{uA}$ | 500 | 1120 |
| Output power switch Leakage Current, uA | $\mathrm{I}_{\text {LEAK }}$ | $\begin{aligned} & \hline \mathrm{U}_{\mathrm{EN}}=0 \mathrm{~V} \\ & \mathrm{U}_{\mathrm{SW}}=0 \mathrm{~V} \\ & \hline \end{aligned}$ |  | 10 |
| Operating frequency, kHz | f |  | 335 | 435 |
| Short Circuit Oscillation Frequency, kHz | F | $\mathrm{U}_{\mathrm{FB}}=0 \mathrm{~V}$ | 25 | 55 |
| Minimum Duty Cycle, \% | $\eta_{\text {MIN }}$ | $\mathrm{U}_{\mathrm{FB}}=1,5 \mathrm{~V}$ |  | 0 |
| EN Threshold Voltage, V | $\mathrm{U}_{\text {EN }}$ |  | 0,9 | 1,5 |
| Bias current, uA | $\mathrm{I}_{\text {IN }}$ | $\mathrm{U}_{\mathrm{EN}}=0 \mathrm{~V}$ | 1,1 | 2,5 |

Table 4 - Typical parameters

| Parameter, unit | Symbol | Mode | Typical <br> value |
| :--- | :---: | :---: | :---: |
| Error Amplifier Voltage Gain, V | K |  | 400 |
| Power output switch ON resistance, mOhm | R 1 |  | 100 |
| Pumping transistor ON resistance, Ohm | $\mathrm{R}_{\mathrm{M} 2}$ |  | 10 |
| Current Sense to COMP Transconductance, $\mathrm{A} / \mathrm{V}$ | $\mathrm{S}_{\mathrm{COMP}}$ |  | 3,8 |
| Maximum Duty Cycle, $\%$ | $\eta_{\mathrm{MAX}}$ | $\mathrm{U}_{\mathrm{FB}}=1,0 \mathrm{~V}$ | 90 |
| Under Voltage Lockout Threshold Hysteresis, mV | $\mathrm{U}_{\mathrm{HIS}}$ |  | 210 |
| Soft Start Period, ms | $\mathrm{t}_{\mathrm{SS}}$ | $\mathrm{C}_{\mathrm{SS}}=10 \mathrm{uF}$ | 10 |
| Current limit, A | $\mathrm{I}_{\mathrm{LIM}}$ |  | 5,5 |
| Thermal shutdown threshold, ${ }^{\circ} \mathrm{C}$ | $\mathrm{T}_{\mathrm{S}}$ |  | 160 |



Fig 2 - Application diagram
SS
GND
COMP

